

■ PRODUCT CHARACTERISTICS

VDSS	-40V
$R_{DS(on)typ}(@V_{GS}=-4.5V)$	13mΩ
$R_{DS(on)typ}(@V_{GS}=-10V)$	10mΩ
ID	-30A

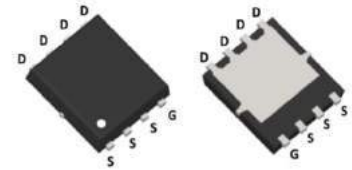
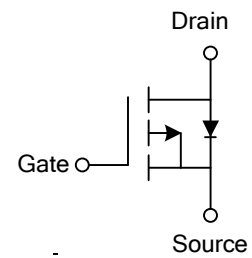
■ FEATURES

Advanced Trench Technology  
Excellent  $R_{DS(ON)}$  and Low Gate Charge  
Lead free product is acquired

■ APPLICATION

PWM Applications  
Load Switch  
Power Management

Symbol



PDFN3X3-8L

■ ORDER INFORMATION

Order codes		Package	Packing
Halogen-Free	Halogen		
N/A	MOT4712J	PDFN3X3-8L	5000 pieces /Reel

■ ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub>=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DSS</sub>	-40	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V
Continuous Drain Current	I <sub>D</sub>	T <sub>C</sub> = 25°C	-30
		T <sub>C</sub> = 100°C	-20
Pulsed Drain Current	I <sub>DM</sub>	-120	A
Single Pulsed Avalanche Energy	E <sub>AS</sub>	110	mJ
Power Dissipation	P <sub>D</sub>	20	W
Thermal Resistance, Junction to Case	R <sub>θJC</sub>	6.3	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## ELECTRICAL CHARACTERISTICS ( p )

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Off characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-40	-	-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-40V, V_{GS}=0V$	-	-	-1	$\mu A$
Gate to Body Leakage Current	$I_{GSS}$	$V_{DS}=0V, V_{GS}=\pm 20V$	-	-	$\pm 100$	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1.0	-1.5	-2.5	V
Static Drain-Source on-Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-20A$	-	10	12.5	m $\Omega$
		$V_{GS}=-4.5V, I_D=-10A$	-	13	17	
Dynamic characteristics						
Input Capacitance	$C_{iss}$	$V_{DS}=-20V, V_{GS}=0V,$ $f=1.0MHz$	-	3700	-	pF
Output Capacitance	$C_{oss}$		-	340	-	pF
Reverse Transfer Capacitance	$C_{rss}$		-	290	-	pF
Total Gate Charge	$Q_g$	$V_{DS}=-20V, I_D=-20A,$ $V_{GS}=-10V$	-	68	-	nC
Gate-Source Charge	$Q_{gs}$		-	10	-	nC
Gate-Drain("Miller") Charge	$Q_{gd}$		-	14	-	nC
Switching characteristics						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=-20V, I_D=-20A,$ $V_{GS}=-10V, R_{GEN}=2.4\Omega$	-	10	-	ns
Turn-on Rise Time	$t_r$		-	82	-	ns
Turn-off Delay Time	$t_{d(off)}$		-	93	-	ns
Turn-off Fall Time	$t_f$		-	74	-	ns
Drain-source diode characteristics and maximum ratings						
Maximum Continuous Drain to Source Diode Forward Current	$I_S$		-	-	-30	A
Maximum Pulsed Drain to Source Diode Forward Current	$I_{SM}$		-	-	-120	A
Drain to Source Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V, I_S=-30A$	-	-0.8	-1.2	V
Reverse Recovery Time	$t_{rr}$	$V_{GS}=0V, I_S=-30A,$ $di/dt=100A/\mu s$	-	20	-	ns
Reverse Recovery Charge	$Q_{rr}$		-	13	-	nC

■ TYPICAL CHARACTERISTICS

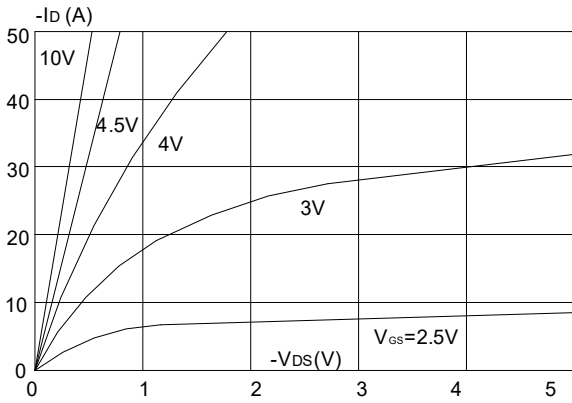


Figure1: Output Characteristics

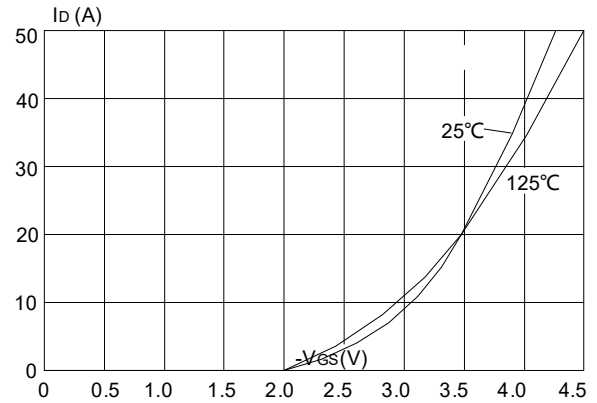


Figure2: Typical Transfer Characteristics

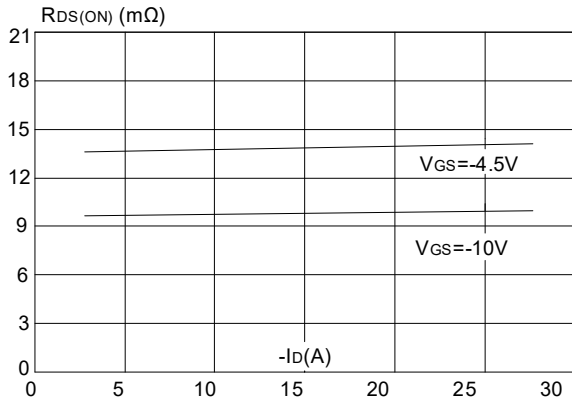


Figure3: On-resistance vs. Drain Current

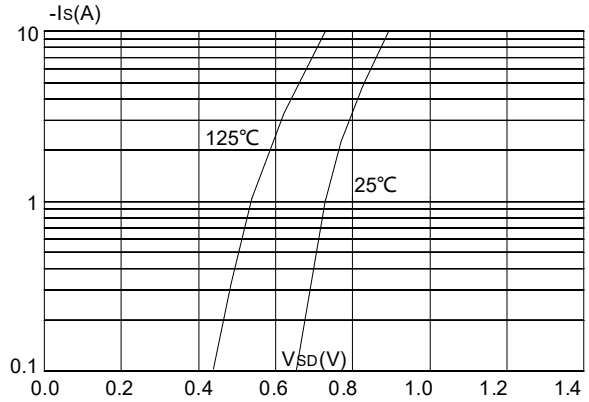


Figure4: Body Diode Characteristics

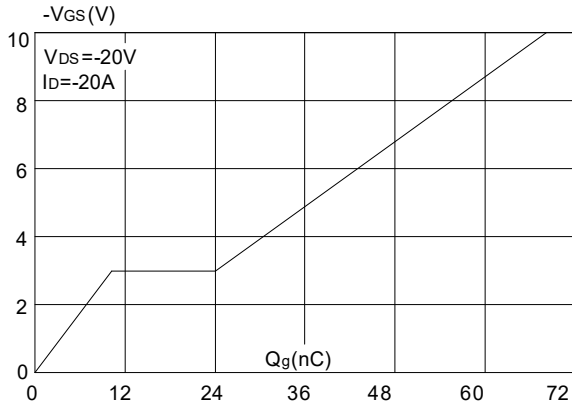


Figure5: Gate Charge Characteristics

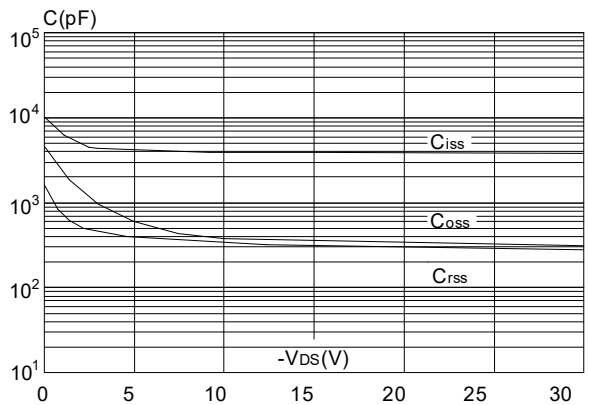


Figure6: Capacitance Characteristics

■ TYPICAL CHARACTERISTICS(Cont.)

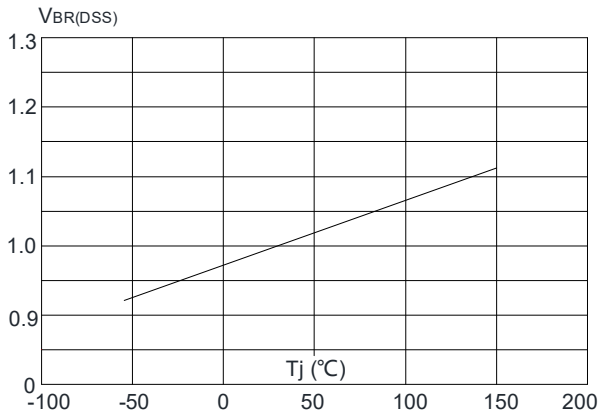


Figure7 : Normalized Breakdown Voltage vs. Junction Temperature

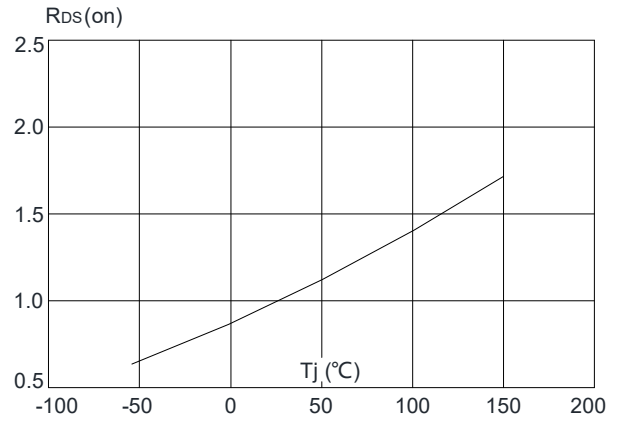


Figure8 : Normalized on Resistance vs. Junction Temperature

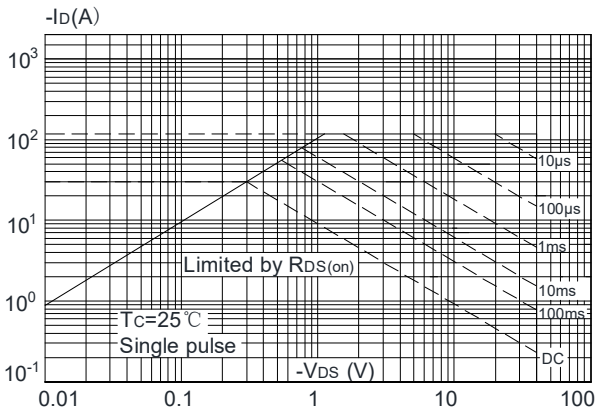


Figure9 : Maximum Safe Operating Area

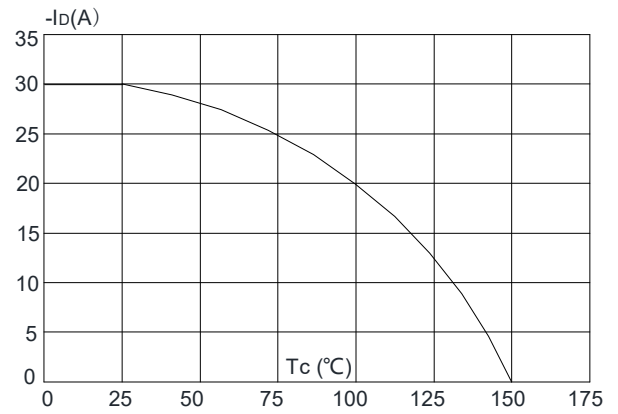


Figure10: Maximum Continuous Drain Current vs. Case Temperature

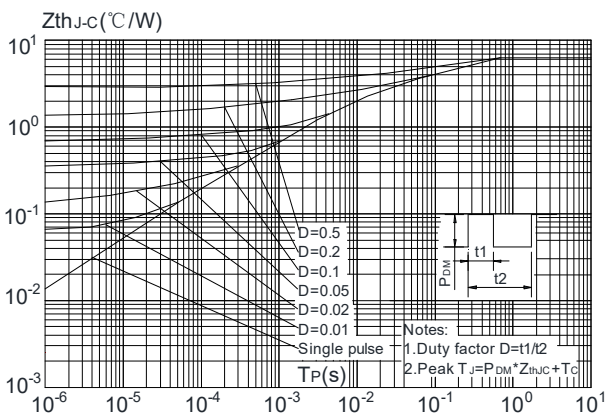
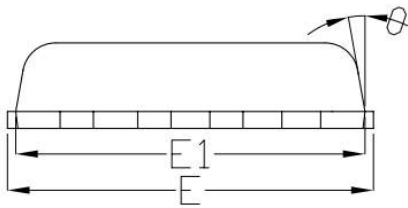
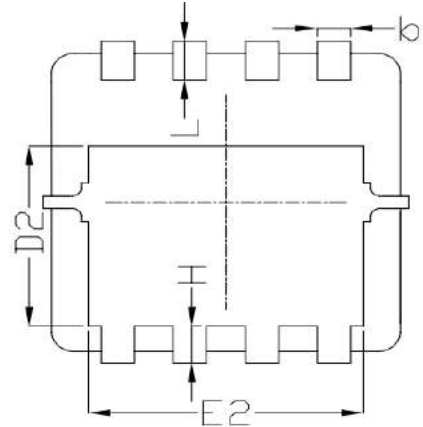
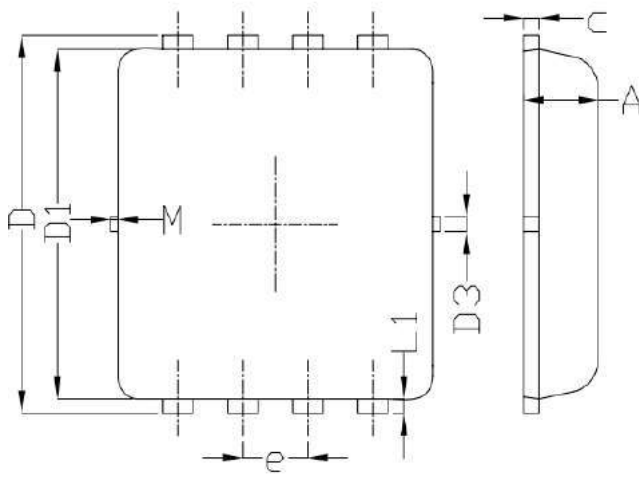
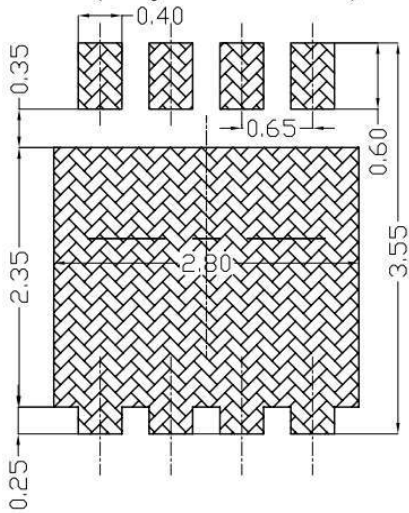


Figure11: Maximum Effective Transient Thermal Impedance, Junction-to-Case

■ PDFN3X3-8L Package Mechanical Data



Land Pattern  
(Only for Reference)



SYMBOL	DIMENSIONAL REOMTS		
	MIN	NOM	MAX
A	0.70	0.75	0.80
b	0.25	0.30	0.35
c	0.10	0.15	0.25
D	3.25	3.35	3.45
D1	3.00	3.10	3.20
D2	1.78	1.88	1.98
D3	---	0.13	---
E	3.20	3.30	3.40
E1	3.00	3.15	3.20
E2	2.39	2.49	2.59
e	0.65BSC		
H	0.30	0.39	0.50
L	0.30	0.40	0.50
L1	---	0.13	---
θ	---	10°	12°
M	*	*	0.15
* Not specified			

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